

Obsolete

B45196P, Tantalum, MnO₂ Tantalum, High Temperature, 33 uF, 10%, 10 VDC, SMD, Molded, High Temperature, N/A, 900 mOhms, 6032, Height Max = 2.8mm



General Information

| | |
|-------------|---|
| Series | B45196P |
| Dielectric | MnO ₂ Tantalum |
| Style | SMD Chip |
| Description | SMD, Molded, High Temperature |
| Features | High Temperature |
| RoHS | Yes |
| Termination | Tin |
| AEC-Q200 | No |
| Notes | Obsolete. Old Part Number [Obsolete] Was B45196P2336K306. |

Specifications

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|-----------------------|---|
| Capacitance | 33 uF |
| Capacitance Tolerance | 10% |
| Voltage DC | 10 VDC (85C), 7.97 VDC (125C), 6.7 VDC (150C) |
| Temperature Range | -55/+150°C |
| Rated Temperature | 85°C |
| Dissipation Factor | 4.5% |
| Failure Rate | N/A |
| Resistance | 0.9 Ohms (100kHz) |
| Leakage Current | 3.3 uA |

Dimensions

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|-----------|----------------|
| Footprint | 6032 |
| L | 6mm +/-0.3mm |
| W | 3.2mm +/-0.3mm |
| H | 2.5mm +/-0.3mm |
| S | 1.3mm +/-0.3mm |
| F | 2.2mm +/-0.1mm |
| K | 1.8mm TYP |

Packaging Specifications

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|--------------------|------------|
| Packaging | T&R, 330mm |
| Packaging Quantity | 3000 |